Using the first principles calculations, we have studied the atomic and electronic structures of single Co atom incorporated with divacancy in armchair graphene nanoribbon (AGNR). Our calculated results show that the Co atom embedded in AGNR gives rise to significant impacts on the band structures and the FM spin configuration is the ground state. The presence of the Co doping could introduce magnetic properties. The calculated results revealed the arising of spin gapless semiconductor characteristics with doping near the edge in both ferromagnetic (FM) and antiferromagnetic (AFM) magnetic configurations, suggesting the robustness for potential application of spintronics. Moreover, the electronic structures of the Co-doped AGNRs are strongly dependent on the doping sites and the edge configurations.

1. Introduction

Graphene is a hexagonal lattice which consists of single atomic layer of sp² hybridized carbon atoms. Owing to its novel properties arising from the truly two-dimensional nanostructure, graphene has attracted extensive theoretical and experimental investigations since its fabrication in 2004 [1]. The unique electronic and transport properties make the graphene nanomaterial the most promising candidate to be served as the next generation nanodevices to replace silicon-based devices [2]. However, its gapless band structure is a major obstacle for the practical application of graphene in the semiconductor area. As a result, considerable efforts are devoted to opening a moderate band gap for the graphene-based nanomaterials, and many approaches have been proposed in the last decade. More specifically, it has been shown that graphene can be lithographically patterned into quasi one-dimensional graphene nanoribbons (GNRs), and the gap opening can be achieved by the quantum confinement effect in GNRs. The atomic configurations at graphene edge can be characterized by transmission electron microscopy (TEM) and scanning tunneling microscopy (STM) [3]. According to the morphology of graphene edges, the GNRs are conventionally classified into two kinds, namely, armchair edge and zigzag edge [4]. Previous reports have demonstrated that the electronic properties of the GNRs are fundamentally dominated by the atomic arrangement pattern of their edges [5, 6].

Application of GNRs for spintronic devices has been limited by their nonmagnetic (NM) characteristics [7]. The introducing of magnetic properties has become one of the most important issues to be investigated. The theoretical research reported previously has shown that the achievement of magnetic properties in graphene nanomaterial can be realized by means of transition metal (TM) atom doping [8]. Correspondingly, experimental fabrication of Fe [9, 10] and Co [11, 12] in graphene nanomaterials and the characterization of their magnetic properties have been implemented. In general, there are two routes to introduce TM in graphene and GNRs: adsorption of the TM atom on graphene sheets directly [13-18] and embedment of the TM atom in vacancy defects [19-22]. Although the adsorption of TM atoms on
the surface of graphene has large binding energy [17], the doping atom cannot be tightly trapped at room temperature as a result of low migration barrier [19]. Therefore, the migration of the TM in graphene nanostructures limits their application in spintronic devices. In sharp contrast, the TM atoms could incorporate with graphene vacancy, such as single vacancy (SV) [23] and double vacancy (DV) [7]. Hence, TM atoms embedded in vacancy defects have larger binding energy than those adsorbed on graphene surface [19]. Previous studies have shown that TM DV complex has larger magnetic moments than that of the TM-monovacancy composite [19].

Recently, many investigations about TM incorporated with AGNRs have been conducted, such as Mn [24], Fe [25], and Ni [26]. Previous computational calculations are devoted to the evaluation of electric properties of ZGNRs influenced by the TM doping, such as the doping of Co [7, 21] and Au [27]. In this communication, we report an ab initio study of atomic and electronic structure of Co atoms incorporated in GNR with armchair-shaped edges. The C-C dimer was replaced by Co atoms. We have accessed the influences of Co-DV on the stability and electronic properties associated with various spin configurations of AGNR by using density functional theory calculations. It is found that the presence of the Co doping could introduce magnetic properties and the ferromagnetic coupled spin configuration is the ground state of the Co-doped AGNRs. Moreover, the electronic structures of the Co-doped AGNRs are dependent on the doping sites and the edge configurations.

2. Method

The atomic geometry optimizations are implemented by using the density functional theory (DFT) utilized in the code of the Spanish initiative for electronic simulations with thousands of atoms (SIESTA) [28, 29]. Following the previous convention [5], the width of GNRs with armchair-shaped edges is defined on the basis of the number of dimmer lines (N), for example, N-AGNRs. We choose II-AGNR consisting of 4 unit cells as supercell to perform computational calculations of electronic and magnetic properties. The standard norm-conserving Troullier-Martins pseudopotential [30] is used to calculate the interaction between valence electrons and the atomic core. The numerical double-\(\xi\) polarized (DZP) basis set and 200 Ry for plane cutoff energy are chosen in the simulation. The generalized gradient approximation (GGA) in the form of Perdew and Burke and Ernzerhof (PBE) is used to calculate exchange correction term [31]. The relaxation of the structures is converged until the force on each atom is less than 0.01 eV/Å.

3. Results and Discussion

In order to obtain preferential doping positions of Co atom at room temperature, we have calculated various doping sites at electronic temperature 300 K, which are shown in Figure 1. The carbon atoms at the edge are passivated by hydrogen atoms in the pristine model. The Co atom is embedded in the AGNR nanostructure by replacing two adjacent C atoms. The different doping sites, from middle to the edge of the AGNRs, are denoted by symbols B to E. The doped nanostructures are referred to as Co-B-AGNR, Co-C-AGNR, Co-D-AGNR, and Co-E-AGNR in this content.

In the nonmagnetic (NM) states, the structure model is optimized. The optimized results are shown in Figure 2. Figure 2(a) is the optimized pristine model. All the atoms are found to be in plane. Figure 2(b) is the optimized Co-D-AGNR model. It is found that the in-plane structure is...
destroyed, which is similar to the case in the Au doping in ZGNRs [27]. The carbon atoms on the edge tend to move toward the doping atom. Compared to the adjacent C atoms, the height of Co atom has been changed after structural reconstruction. With the Co atoms moving from middle to edge, the edge which is close to the Co atom experiences larger distortion than the other side. The curving structure of the Co-doped GNRs is associated with the presence of the Co atom due to its larger mass in comparison to the carbon atom.

In addition, the simulated scanning tunneling microscopy (STM) images are also presented in Figure 3 [32–34], which could be helpful in identifying the Co doping nanostructure in experiments in future.

In order to identify the ground state of the Co-AGNR influenced by different sites, we have also calculated the total energy of the nanostructures with different magnetic configurations, including the antiferromagnetic (AFM) and the ferromagnetic (FM) coupled states. The spin-related

Figure 2: (a) The optimized pristine AGNR nanostructure. (b) The optimized nanostructure of the D site doping configuration.

Figure 3: Atomic structures (a) and their simulated STM image (b) of the Co-D-AGNR doping configuration.
magnetic configurations are shown in Figure 4, and the nanostructures imposed to AFM and FM states are fully relaxed. The calculated results indicate that all atoms are basically in plane under AFM and FM states. The longest Co-C bond length is 1.93 Å, which is presented in the Co-D-AGNR configuration, and the lowest Co-C bond length is 1.87 Å emerging in the Co-E-AFM configuration. This is in a good agreement with previous calculations carried out in the ZGNRs [7, 21]. The magnetic moments are shown in Table 1.

The total energies of various doping configurations are shown in Figure 5. To analyze the stability of the various magnetic configurations, we thus have calculated the binding energy (BE) by the following equation:

$$E_b = E(\text{Co-AGNR}) + E(\text{C-C}) - E(\text{Co}) - E(\text{AGNR}),$$

(1)

where $E(\text{Co-AGNR})$ is the total energy of Co-AGNR, $E(\text{AGNR})$ is the total energy of the pristine AGNR, $E(\text{C-C})$ is the total energy of C-C dimer in graphene, and $E(\text{Co})$ is the total energy of an isolated Co atom. The BE is summarized in Table 1.

![Figure 4: (a) The reconstructed nanostructure of the Co-D-AGNR at AFM state. (b) The reconstructed nanostructure of the Co-D-AGNR at FM state. The blue and red colors denote opposite spin states.](image)

![Figure 5: The total energy of different Co-doped AGNRs nanostructures at different spin configurations.](image)

**Table 1: The total spin magnetic moments of different Co-doped AGNRs nanostructures at different spin configurations.**

<table>
<thead>
<tr>
<th>Co position</th>
<th>Magnetic state</th>
<th>Magnetic moment ($\mu_B$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>B</td>
<td>AFM</td>
<td>0</td>
</tr>
<tr>
<td></td>
<td>FM</td>
<td>1.988</td>
</tr>
<tr>
<td>C</td>
<td>AFM</td>
<td>1.979</td>
</tr>
<tr>
<td></td>
<td>FM</td>
<td>-1.979</td>
</tr>
<tr>
<td>D</td>
<td>AFM</td>
<td>2.852</td>
</tr>
<tr>
<td></td>
<td>FM</td>
<td>1.976</td>
</tr>
<tr>
<td>E</td>
<td>AFM</td>
<td>-1.924</td>
</tr>
<tr>
<td></td>
<td>FM</td>
<td>1.924</td>
</tr>
</tbody>
</table>
Figure 6: Electronic band structures of Co embedded in AGNRs at different doping sites. (a) and (b) are the spin-polarized results associated with AFM and FM magnetic configurations, respectively. The solid red (dotted blue) line corresponds to spin-up (spin-down) states. The Fermi level is set to zero.

Table 2. Clearly, the Co-D-AGNR configuration has the lowest total energy and the lowest binding energy. Therefore, D site is the most energetically favorable doping configuration. For the D and E doping sites, it is noted that the total energy is almost equal under FM and AFM states. Compared with NM and AFM spin configurations, the total energy in the FM state is the lowest one. The FM state configuration is found to be their ground state of these nanostructures.

The spin-polarized band structures of Co-AGNR in AFM state are exhibited in Figure 6(a). Pristine AGNR is fully degenerate with a band gap of 0.31 eV, which is in excellent agreement with previous study [35]. The band structure of the Co-B-AGNR is degenerate in sharp contrast to the splitting band structures of C–E site doping configuration. The presence of the TM atom in the nanostructure is generally favorable for electron transport by narrowing the electronic...
The calculated total and projected density of states (TDOS and PDOS, resp.) of these doped nanostructures are shown in Figure 7. In accordance with the electronic band structures described above, the PDOS and the TDOS of the Co-B-AGNR are degenerate for opposite spin states. There occurs a peak at −1 eV both in the TDOS and PDOS, which is consistent with the presence of flat band at this location in the electronic band structure, as shown in Figure 6(a). Here, the localized states in this vicinity thus can be attributed to the Co atom and its contributions to the opposite spin states are almost equivalent. For the Co-C-AGNR under AFM state, the opposite spin states at −0.38 eV are observed to have distinct differences. And the localized state in the electronic band structure can be recognized to the spin-down state influenced by the Co doping. Hence, for the Co-E-AGNR under AFM state, the presence of the TM doping gives rise to the two flat bands at −0.5 eV and −0.9 eV in the spin-up band structure. For the FM magnetic configurations, the PDOS are splitting for the Co-B-AGNR nanostructure, which is consistent with the nondegenerate bands around the Fermi level. For the C, D, and E doping sites, it is interesting to find that the opposite states in PDOS are flipped. In brief, our calculations of TDOS and PDOS indicate that the Co atom could have pronounced influences on the electronic structures around the Fermi level that are favorable for electronic transport, which are dependent on the doping sites.

### 4. Conclusions

We have performed computational calculations to study the influences of single Co atom doping on the electronic structures of the 11-AGNRs. The FM spin configuration is the ground state for all doped sites. Our calculated results revealed that the Co-D-AGNR is the most stable doping configuration, and the electronic transport properties of this nanostructure can be tuned between spin gapless semiconductor and gapped nanomaterial by changing magnetic states. In addition, the Co-E-AGNR keeps spin gapless semiconductor characteristics in both FM and AFM states, exhibiting the robustness for potential application of spintronics. The embedding of Co atoms in the AGNRs leads to the downward shift of Fermi level and gives rise to significant impacts on their electronic band structures. The electronic structures of Co-doped AGNRs are strongly dependent on the doping sites and the edge configurations.

### Conflict of Interests

The authors declare that there is no conflict of interests regarding the publication of this paper.

### Acknowledgments

The authors are grateful to Dr. J.-W. Wei for helpful discussions, Professor Ma for assistance on calculations in the High Performance Computing Center of Nanjing University, and Dr. Y.-H. Zhao for performing partial simulations in HPCC@SICNU. This work is financially supported by the Natural Science Foundation of China (Grant nos. 11304022,
Figure 7: Total (black line) and projected (red line) density of states of the Co-B-AGNR, Co-C-AGNR, Co-D-AGNR, and Co-E-AGNR under different magnetic configurations. (a) and (b) are the spin-polarized results associated with AFM and FM magnetic configurations, respectively. Spin-up and spin-down states are denoted by positive and negative values, respectively. The Fermi level is set to zero.
References


Submit your manuscripts at
http://www.hindawi.com